

WNS40H100C Dual power Schottky diode

Rev.02 - 01 August 2022

Product data sheet

1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO220 plastic package.

2. Features and benefits

- Trench structure
- High junction temperature up to 150 °C
- High efficiency
- Low forward voltage drop, negligible switching losses

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode

4. Quick reference data

	uick reference data						
Symbol	Parameter	Conditions	Values				Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage		100			V	
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 134 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	20			А	
O(AV)	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 131 °C; both diodes conducting	40			A	
Symbol	Parameter	Conditions	Min Typ Ma		Max	Unit	
Static cha	aracteristics	·					
V _F forward voltage		I _F = 10 A; T _j = 25 °C; prediode; <u>Fig. 6</u>		-	0.54	0.59	V
		I _F = 10 A; T _j = 125 °C; prediode; <u>Fig. 6</u>		-	0.5	0.56	V
		I _F = 20 A; T _j = 25 °C; prediode; <u>Fig. 6</u>		-	0.67	0.71	V
		I _F = 20 A; T _j = 125 °C; prediode; <u>Fig. 6</u>		-	0.63	0.68	V
R	reverse current	V _R = 100 V; T _j = 25 °C; <u>Fig. 7</u>		-	-	50	μA
		V _R = 100 V; T _j = 125 °C; <u>Fig. 7</u>		-	-	30	mA

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode 1	mb	
2	K	cathode	1 205	
3	А	anode 2		
mb	mb	mounting base; connected to cathode		sym125

6. Ordering information

Table 3. Ordering information							
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
WNS40H100C	TO220	WNS40H100C,127	Tube	50	SOT78	13-Jun-2008	

7. Marking

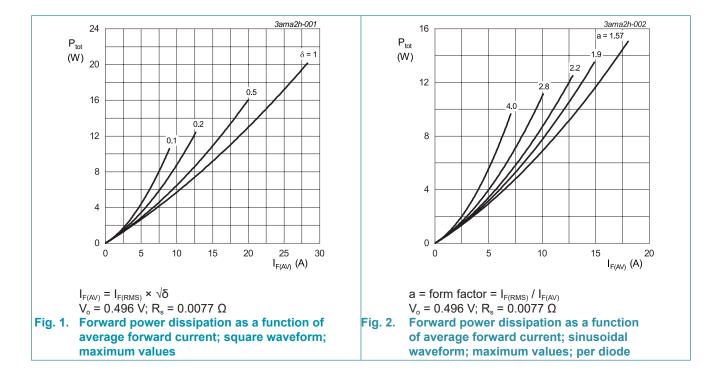
Table 4. Marking codes	
Type number	Marking codes
WNS40H100C	WNS 40H100C

8. Limiting values

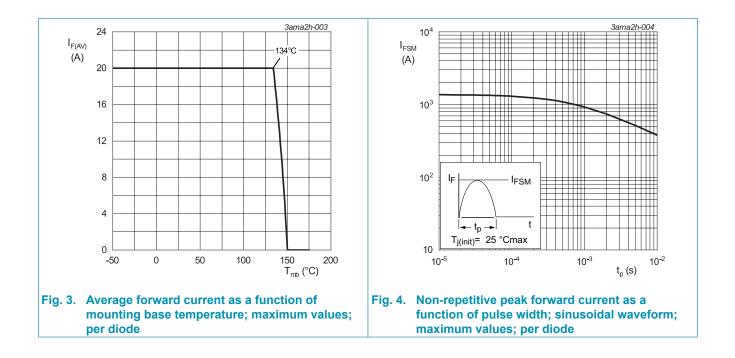
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V _{RRM}	repetitive peak reverse voltage		100	V
V _{RWM}	crest working reverse voltage		100	V
V _R	reverse voltage	DC	100	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 134 °C; per diode; Fig. 1; Fig. 2; Fig. 3	20	A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 131 °C; both diodes conducting	40	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4	380	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	418	A
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		150	°C

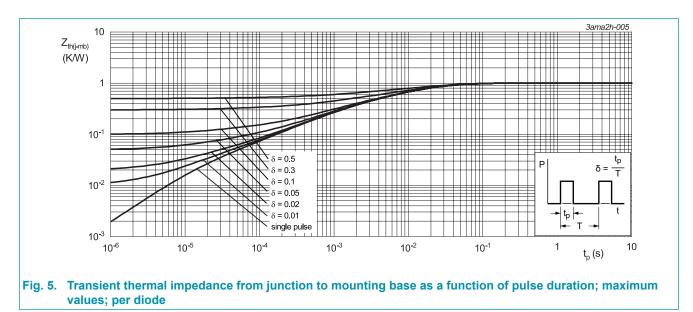


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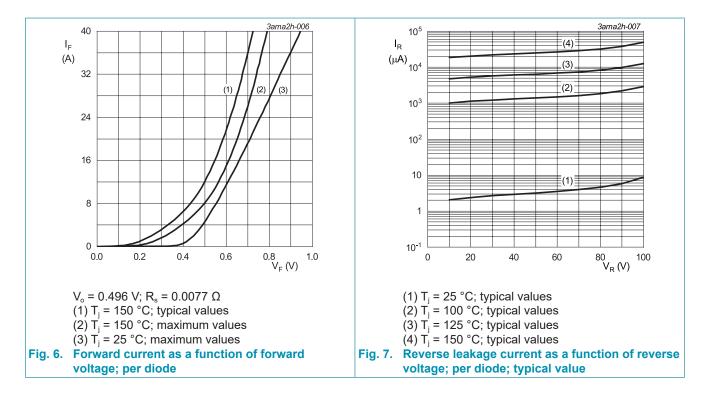
9. Thermal characteristics

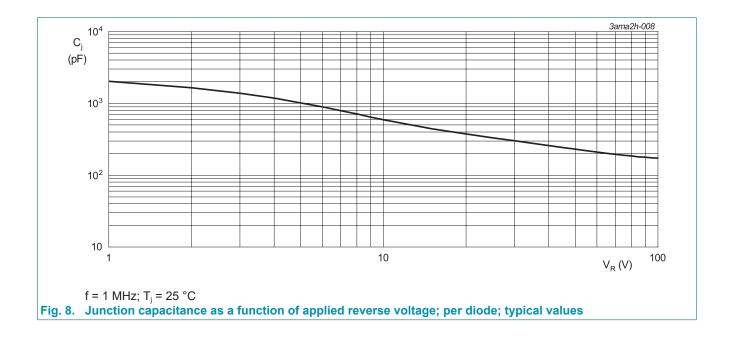
Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th}(j\text{-}mb)}$	thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>	-	-	1	K/W
		both diodes conducting	-	-	0.6	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



10. Characteristics

Table 7. Cł	naracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static cha	racteristics						
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; prediode; <u>Fig. 6</u>		-	0.54	0.59	V
		I _F = 10 A; T _j = 125 °C; prediode; <u>Fig. 6</u>		-	0.5	0.56	V
		$I_{F} = 20 \text{ A}; T_{j} = 25 \text{ °C}; \text{ prediode}; Fig. 6$		-	0.67	0.71	V
		I _F = 20 A; T _j = 125 °C; prediode; <u>Fig. 6</u>		-	0.63	0.68	V
Ι _R	reverse current	V _R = 100 V; T _j = 25 °C; prediode; <u>Fig. 7;</u> <u>Fig. 8</u>		-	-	50	μA
		V _R = 100 V; T _j = 125 °C; prediode; <u>Fig. 7;</u> <u>Fig. 8</u>		-	-	30	mA

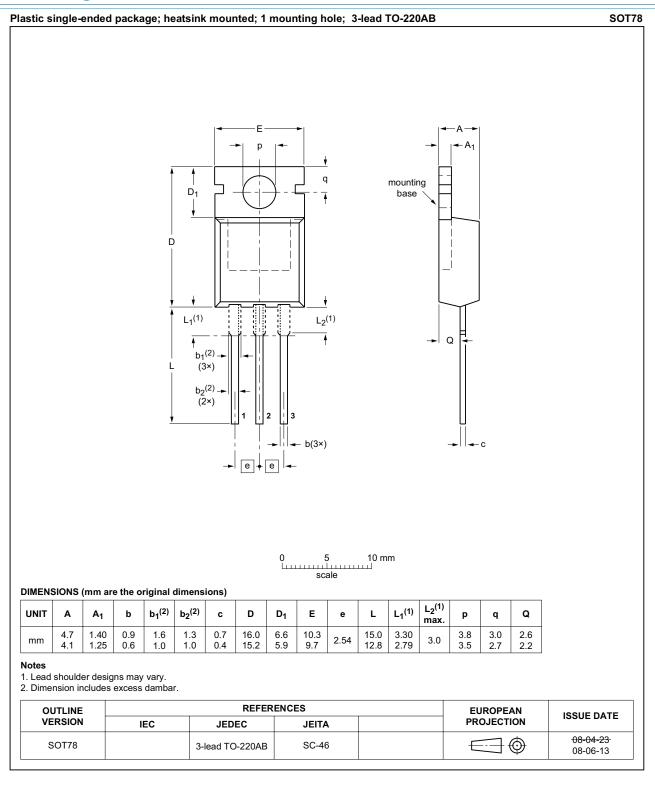




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Dual power Schottky diode

11. Package outline



WNS40H100C Product data sheet

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Dual power Schottky diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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